











TPA6138A2

SLOS704B - JANUARY 2011 - REVISED AUGUST 2015

TPA6138A2 DirectPath[™] Headphone Driver With Adjustable Gain

Features

- Stereo DirectPath™ Headphone Amplifier - 40 mW Into 32 Ω With 3.3-V Supply
- Low THD+N < 0.01% at 10 mW Into 32 Ω
- High SNR, >90 dB
- Differential Input and Single-Ended Output
- Adjustable Gain by External Gain-Setting Resistors
- Configurable as a Second-Order Low-Pass Filter
 - Ideal for PWM Audio Sources
- Low DC Offset, <1 mV
- Ground-Referenced Outputs Eliminate DC-**Blocking Capacitors**
 - Reduce Board Area
 - Reduce Component Cost
 - Improve THD+N Performance
 - No Degradation of Low-Frequency Response **Due to Output Capacitors**
- Short-Circuit Protection
- Click- and Pop-Reduction Circuitry
- External Undervoltage Mute
- Active Mute Control for Pop-Free Audio On/Off Control
- Space-Saving TSSOP Package

Applications

- LCD and PDP TV
- Blu-ray Disc™, DVD Players
- Set-Top Boxes
- Mini/Micro Combo Systems
- Sound Cards
- Laptops

3 Description

The TPA6138A2 is a pop-free stereo headphone amplifier designed to allow the removal of the output dc-blocking capacitors for reduced component count and cost. The device is ideal for single-supply electronics where size and cost are critical design parameters.

patented Designed using TI's DirectPath™ technology, The TPA6138A2 is capable of driving 25 mW into a 32- Ω load with 3.3-V supply voltage. The device has differential inputs and uses external gainsetting resistors that supports a gain range of ±1 V/V to ±10 V/V. Gain can be configured individually for each channel. The device can also be configured as a second-order low-pass filter and is ideal for interfacing with PWM audio sources. Audio output compiles with ±8-kV IEC ESD protection, requiring just a simple resistor-capacitor ESD protection circuit. The TPA6138A2 has built-in active-mute control for pop-free audio on/off control. The TPA6138A2 has an external undervoltage detector that mutes the output when the power supply is removed, ensuring a popfree shutdown.

Using the TPA6138A2 in audio products can reduce component count considerably compared traditional headphone amplifiers. The TPA6138A2 does not require a split-rail power supply or a dc blocking capacitor. The TPA6138A2 integrates its own charge pump to generate a negative supply rail that provides a clean, pop-free ground-biased audio signal.

The TPA6138A2 is available in a 14-pin TSSOP.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPA6138A2	TSSOP (14)	5.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Diagram

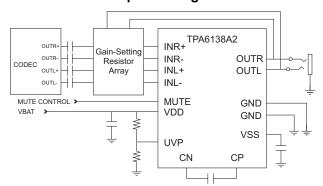




Table of Contents

1	Features 1		9.2 Functional Block Diagram	8
2	Applications 1		9.3 Feature Description	8
3	Description 1		9.4 Device Functional Modes	9
4	Revision History2	10	Application and Implementation	11
5	Device Comparison Table3		10.1 Application Information	11
6	Pin Configuration and Functions		10.2 Typical Application	12
7	Specifications4	11	Power Supply Recommendations	13
•	7.1 Absolute Maximum Ratings	12	Layout	14
	7.2 ESD Ratings		12.1 Layout Guidelines	14
	7.3 Recommended Operating Conditions		12.2 Layout Example	14
	7.4 Thermal Information	13	Device and Documentation Support	15
	7.5 Electrical Characteristics		13.1 Device Support	15
	7.6 Operating Characteristics		13.2 Community Resources	15
	7.7 Typical Characteristics		13.3 Trademarks	15
8	Parameter Measurement Information 7		13.4 Electrostatic Discharge Caution	15
9	Detailed Description 7		13.5 Glossary	15
•	9.1 Overview	14	Mechanical, Packaging, and Orderable Information	15

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (May 2011) to Revision B

Page

Changes from Original (January 2011) to Revision A

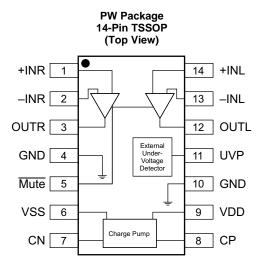
Page



5 Device Comparison Table

	TPA6138A2	TPA6130A2	TPA6132A2	TPA6133A2	TPA6136A2	TPA6140A2	TPA6141A2
Ground-Centered Outputs	Yes	Yes	Yes	Yes	Yes	Yes	Yes
Class-G	-	_	-	_	_	Yes	Yes
Special Features	Adj. Gain	=	Gain Select	Fixed Gain	Gain Select	-	Gain Select
Volume Control	-	Yes	-	_	_	Yes	_
Headphone Channels	Stereo	Stereo	Stereo	Stereo	Stereo	Stereo	Stereo
Output Power (W)	0.25	0.138	0.025	0.138	0.025	0.025	0.025
PSRR (dB)	80	109	100	109	100	105	105

6 Pin Configuration and Functions



Pin Functions

	PIN TYPE ⁽¹⁾		DESCRIPTION	
NAME	NO.	ITPE\"	DESCRIPTION	
CN	7	I/O	Charge-pump flying capacitor negative connection	
СР	8	I/O	Charge-pump flying capacitor positive connection	
GND	4, 10	Р	Ground	
-INL	13	I	-channel OPAMP negative input	
+INL	14	I	Left-channel OPAMP positive input	
-INR	2	I	Right-channel OPAMP negative input	
+INR	1	I	ght-channel OPAMP positive input	
Mute	5	I	ute, active-low	
OUTL	12	0	t-channel OPAMP output	
OUTR	3	0	Right-channel OPAMP output	
UVP	11	I	Undervoltage protection; internal pull-up, unconnected if UVP function is unused.	
VDD	9	Р	Positive supply	
VSS	6	Р	Supply voltage	

(1) I = input, O = output, P = power



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
V _{DD} to GND	-0.3	4	V
Input voltage, V _I	V _{SS} - 0.3	$V_{DD} + 0.3$	V
Minimum load impedance – line outputs – OUTL, OUTR		12.8	Ω
Mute to GND, UVP to GND	-0.3	V _{DD} +0.3	V
Maximum operating junction temperature range, T _J	-40	150	°C
Storage temperature range, T _{stg}	-40	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	\/
V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V_{DD}	Power supply	DC supply voltage	3	3.3	3.6	٧
R_L	Load impedance		16	32		Ω
V_{IL}	Low-level input voltage	Mute		40		%VDD
V_{IH}	High-level input voltage	Mute		60		%VDD
T _A	Ambient temperature	· ·	-40	25	85	ů

7.4 Thermal Information

		TPA6138A2	
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	UNIT
		14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	130	°C/W
R ₀ JC(top)	Junction-to-case (top) thermal resistance	49	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	63	°C/W
ΨЈТ	Junction-to-top characterization parameter	3.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	62	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

 $V_{DD}=3.3~V,~R_{DL}=32~\Omega,~R_{fb}=30~k\Omega,~R_{IN}=15~k\Omega,~T_{A}=25^{\circ}C,~Charge~pump:~C_{P}=1~\mu F~(unless~otherwise~noted)$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OS}	Output offset voltage	V _{DD} = 3.3 V		0.5	1	mV
PSRR	Power-supply rejection ratio			80		dB
V _{OH}	High-level output voltage	V _{DD} = 3.3 V	3.1			V
V_{OL}	Low-level output voltage	V _{DD} = 3.3 V			-3.05	V
V_{UVP_EX}	External UVP detect voltage			1.25		V
V _{UVP_EX_HYSTERESIS}	External UVP detect hysteresis current			5		μΑ
f_{CP}	Charge-pump switching frequency		200	300	400	kHz
Пн	High-level input current, Mute	V_{DD} = 3.3 V, V_{IH} = V_{DD}			1	μΑ
$ I_{IL} $	Low-level input current, Mute	$V_{DD} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$			1	μΑ
		$V_{DD} = 3.3 \text{ V}$, no load, $\overline{\text{Mute}} = V_{DD}$, no load	5	14	25	
I _{DD}	Supply current	$V_{DD} = 3.3 \text{ V, no load, } \overline{\text{Mute}} = \text{GND,}$ disabled		14		mA

7.6 Operating Characteristics

 $V_{DD} = 3.3 \text{ V}$, $R_{DL} = 32 \Omega$, $R_{fb} = 30 \text{ k}\Omega$, $R_{IN} = 15 \text{ k}\Omega$, $T_A = 25 ^{\circ}\text{C}$, Charge pump: $C_P = 1 \mu\text{F}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Po	Output power, outputs in phase	THD+N = 1%, V_{DD} = 3.3 V, f = 1 kHz, R_{L} = 32 Ω		40		mW
THD+N	Total harmonic distortion plus noise	$V_{DD} = 3.3V$, $f = 1kHz$, $R_{LD} = 32\Omega$, $Po = 10mW$		0.01%		
SNR	Signal-to-noise ratio ⁽¹⁾	A-weighted	90	96		dB
DNR	Dynamic range ⁽²⁾	A-weighted	90	100		dB
V _N	Noise voltage	A-weighted		13		μV
Z _O	Output Impedance when muted	Mute = GND		110		mΩ
	Input-to-output attenuation when muted	Mute = GND		80		dB
	Crosstalk—L to R, R to L	Po = 20 mW		-75		dB
I _{LIMIT}	Current limit	PVDD = 3.3 V		50		mA

Product Folder Links: TPA6138A2

⁽¹⁾ SNR is calculated relative to 25-mW output.

⁽²⁾ DNR is calculated relative to output at 1% THD+N.



7.7 Typical Characteristics

 $V_{DD} = 3.3 \; V \; , \; T_{A} = 25 ^{\circ}C, \; C(PUMP) = C(VSS) = 1 \; \mu F \; , \; C_{IN} = 2.2 \; \mu F, \; R_{IN} = 15 \; k\Omega, \; R_{fb} = 30 \; k\Omega, \; R_{OUT} = 10 \; \Omega, \; C_{OUT} = 1 \; nF \; R_{IN} = 10 \; R_{IN$ (unless otherwise noted)

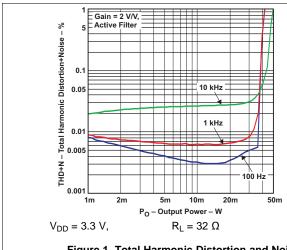


Figure 1. Total Harmonic Distortion and Noise vs Output Power

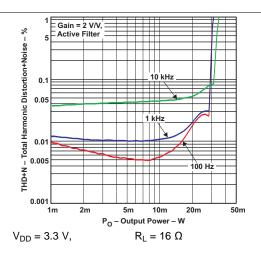


Figure 2. Total Harmonic Distortion and Noise vs Output Voltage

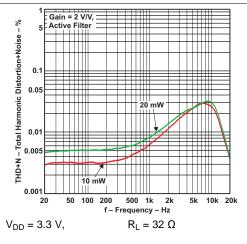


Figure 3. Total Harmonic Distortion and Noise vs Frequency

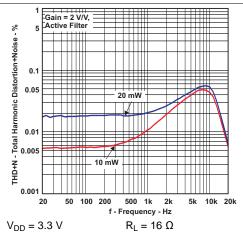


Figure 4. Total Harmonic Distortion and Noise vs Frequency

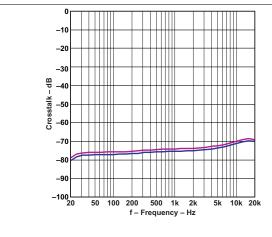
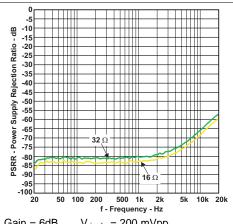


Figure 5. Crosstalk vs Frequency



Gain = 6dB $V_{ripple} = 200 \text{ mVpp}$

Figure 6. Supply Rejection Ratio vs Frequency

Submit Documentation Feedback

Copyright © 2011-2015, Texas Instruments Incorporated



8 Parameter Measurement Information

All parameters are measured according to the conditions described in Specifications.

9 Detailed Description

9.1 Overview

The TPA6138A2 is a DirectPathTM stereo headphone amplifier that requires no output DC blocking capacitors and is capable of delivering 25m-W into a $32-\Omega$ load. The device has built-in pop suppression circuitry to completely eliminate pop noise during turn- on and turn-off. The amplifier outputs have short-circuit protection.

The TPA6138A2 features fully differential inputs to reduce system noise pickup between the audio source and the headphone amplifier. The high power supply noise rejection performance and differential architecture provides increased RF noise immunity.

The TPA6138A2 gain is controlled by external resistors Rin and Rfb, see the *Gain-Setting Resistor Ranges* section for recommended values.

The TPA6138A2 operates from a single 3-V to 3.6-V supply, as it uses a built-in charge pump to generate a negative voltage supply for the headphone amplifiers.

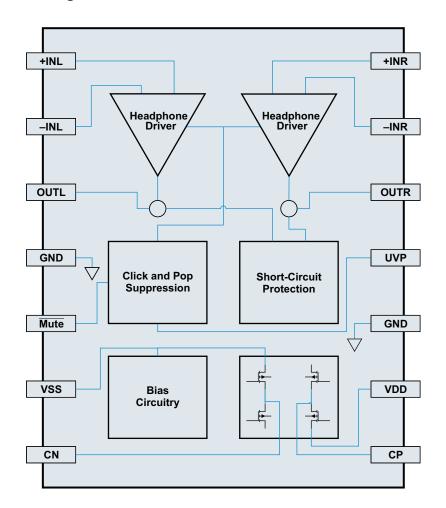
The TPA6138A2 features an external undervoltage protection which must be set according to *TPA6138A2 UVP Operation*.

The TPA6138A2 can also be used as a standard operational amplifier (op amp), this makes possible to configure the device as a second-order low-pass filter to remove out-of-band noise.

Product Folder Links: TPA6138A2



9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Direct Path Headphone Driver

Single-supply line-driver amplifiers typically require dc-blocking capacitors. The top drawing in Figure 7 illustrates the conventional line-driver-amplifier connection to the load and output signal. DC blocking capacitors are often large in value. The headphone load (typical resistive values of 16 Ω to 32 Ω) combine with the dc blocking capacitors to form a high-pass filter. Equation 1 shows the relationship between the load impedance (R_L), the capacitor (C_O), and the cutoff frequency (f_C).

$$f_{c} = \frac{1}{2\pi R_{L} C_{O}} \tag{1}$$

Co can be determined using Equation 2, where the load impedance and the cutoff frequency are known.

$$C_{O} = \frac{1}{2\pi R_{L} f_{c}} \tag{2}$$

If f_C is low, the capacitor must then have a large value because the load resistance is small. Large capacitance values require large package sizes. Large package sizes consume PCB area, stand high above the PCB, increase cost of assembly, and can reduce the fidelity of the audio output signal.



Feature Description (continued)

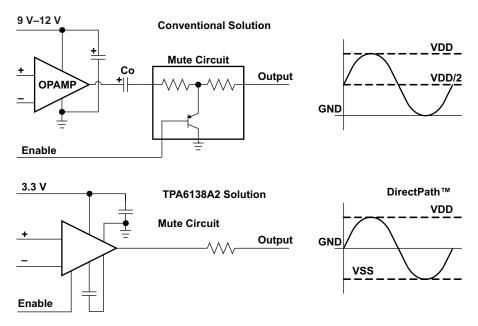


Figure 7. Conventional and DirectPath Line Driver

The DirectPath amplifier architecture operates from a single supply but makes use of an internal charge pump to provide a negative voltage rail. Combining the user-provided positive rail and the negative rail generated by the IC, the device operates in what is effectively a split-supply mode. The output voltages are now centered at zero volts with the capability to swing to the positive rail or negative rail. The DirectPath amplifier requires no output dc-blocking capacitors. The bottom block diagram and waveform of Figure 7 show the ground-referenced line-driver architecture. This is the architecture of the TPA6138A2.

9.4 Device Functional Modes

9.4.1 Mute Operation

The TPA6138A2 is able to turn off the output transistors by asserting to low level the Mute pin. This option is useful when an idle state is needed.

9.4.2 Using the TPA6138A2 as a Second-Order Filter

Several audio DACs used today require an external low-pass filter to remove out-of-band noise. This is possible with the TPA6138A2, as it can be used like a standard OPAMP. Several filter topologies can be implemented, both single-ended and differential. In Figure 8, a multi-feedback (MFB) topology with differential input and single-ended input is shown.

An ac-coupling capacitor to remove dc content from the source is shown; it serves to block any dc content from the source and lowers the dc gain to 1, helping to reduce the output dc offset to a minimum.

Product Folder Links: TPA6138A2

To calculate the component values, use the TI WEBENCH® Filter Designer (www.ti.com/filterdesigner)

porated Submit Documentation Feedback



Device Functional Modes (continued)

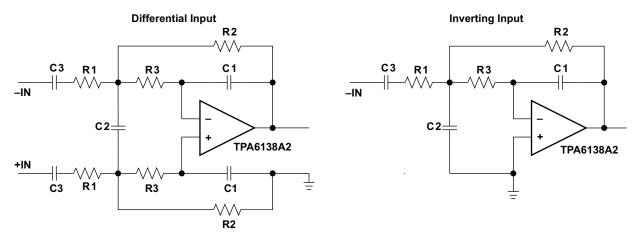


Figure 8. Second-Order Active Low-Pass Filter

The resistor values should have a low value for obtaining low noise, but should also have a high enough value to allow use of a small-size ac-coupling capacitor. With the proposed values of 15 k Ω , 30 k Ω , and 43 k Ω , a dynamic range (DYR) of 106 dB can be achieved with a 1- μ F input ac-coupling capacitor.

9.4.3 TPA6138A2 UVP Operation

The shutdown threshold at the UVP pin is 1.25 V. The customer must use a resistor divider to obtain the shutdown threshold and hysteresis desired for a particular application. The customer-selected thresholds can be determined as follows:

$$V_{UVP} = (1.25 - 6 \mu A \times R3) \times (R1 + R2) / R2$$
 (3)
Hysteresis = $5 \mu A \times R3 \times (R1 + R2) / R2$ (4)

For example, to obtain $V_{UVP}=3.8~V$ and 1-V hysteresis, we can use R1 = 3 k Ω , R2 = 1 k Ω and R3 = 50 k Ω .

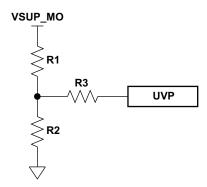


Figure 9. UVP Resistor Divider



10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The TPA6138A2 starts its operation by asserting the MUTE pin to logic 1. The device enters in mute mode when pulling low MUTE pin. The charge pump generates a negative supply voltage. The charge pump flying capacitor connected between CP and CN transfers charge to generate the negative supply voltage. The output voltages are capable of positive and negative voltage swings and are centered close to 0 V, eliminating the need for output capacitors. Input coupling capacitors block any dc bias from the audio source and ensure maximum dynamic range. The device has built-in pop suppression circuitry to completely eliminate pop noise during turnon, turn-off and enter or exit shutdown mode.

10.1.1 Gain-Setting Resistor Ranges

The gain-setting resistors, R_{IN} and R_{fb} , must be chosen so that noise, stability, and input capacitor size of the TPA6138A2 are kept within acceptable limits. Voltage gain is defined as R_{fb} divided by R_{IN} .

Selecting values that are too low demands a large input ac-coupling capacitor, C_{IN} . Selecting values that are too high increases the noise of the amplifier. Table 1 lists the recommended resistor values for different inverting-input gain settings.

GAIN	INPUT RESISTOR VALUE, R _{IN}	FEEDBACK RESISTOR VALUE, R _{fb}
-1 V/V	10 kΩ	10 kΩ
−1.5 V/V	8.2 kΩ	12 kΩ
-2 V/V	15 kΩ	30 kΩ
-10 V/V	4.7 kΩ	47 kΩ

Table 1. Recommended Resistor Values

10.1.2 Input-Blocking Capacitors

DC input-blocking capacitors are required to be added in series with the audio signal into the input pins of the TPA6138A2. These capacitors block the dc portion of the audio source and allow the TPA6138A2 inputs to be properly biased to provide maximum performance.

These capacitors form a high-pass filter with the input resistor, R_{IN} . The cutoff frequency is calculated using Equation 5. For this calculation, the capacitance used is the input-blocking capacitor and the resistance is the input resistor chosen from Table 1; then the frequency and/or capacitance can be determined when one of the two values is given.

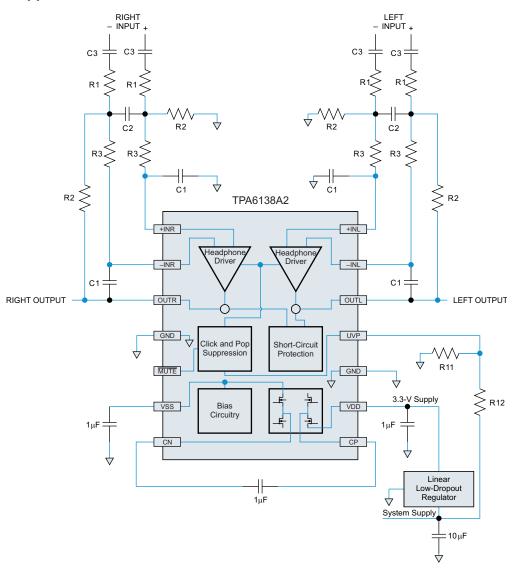
It is recommended to use electrolytic capacitors or high-voltage-rated capacitors as input blocking capacitors to ensure minimal variation in capacitance with input voltages. Such variation in capacitance with input voltages is commonly seen in ceramic capacitors and can increase low-frequency audio distortion.

$$f_{cIN} = \frac{1}{2\pi R_{IN} C_{IN}}$$
 or $C_{IN} = \frac{1}{2\pi f_{cIN} R_{IN}}$ (5)

Copyright © 2011–2015, Texas Instruments Incorporated



10.2 Typical Application



R1 = 15 k $\Omega,~R2$ = 30 k $\Omega,~R3$ = 43 k $\Omega,~C1$ = 47 pF, C2 = 180 pF

Figure 10. Typical Application Schematic

10.2.1 Design Requirements

This typical application requires the parameters listed in Table 2.

Table 2. Design Parameters

PARAMETER	VALUES
Input voltage range	3 V to 3.6 V
Current	14 mA to 25 mA



10.2.2 Detailed Design Procedure

10.2.2.1 Charge-Pump Flying Capacitor and VSS Capacitor

The charge-pump flying capacitor serves to transfer charge during the generation of the negative supply voltage. The VSS capacitor must be at least equal to the charge-pump capacitor in order to allow maximum charge transfer. Low-ESR capacitors are an ideal selection, and a value of 1 μ F is typical. Capacitor values that are smaller than 1 μ F can be used, but the maximum output voltage may be reduced, and the device may not operate to specifications. If the TPA6138A2 is used in highly noise-sensitive circuits, it is recommended to add a small LC filter on the V_{DD} connection.

10.2.2.2 Decoupling Capacitors

The TPA6138A2 is a DirectPath headphone amplifier that requires adequate power-supply decoupling to ensure that the noise and total harmonic distortion (THD) are low. A good low equivalent-series-resistance (ESR) ceramic capacitor, typically 1 μ F, placed as close as possible to the device V_{DD} lead works best. Placing this decoupling capacitor close to the TPA6138A2 is important for the performance of the amplifier. For filtering lower-frequency noise signals, a 10- μ F or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device.

10.2.3 Application Curves

See the curves listed in Table 3 for the application curves.

Table 3. Table of Graphs

	FIGURE
Total Harmonic Distortion and Noise vs Output Power	Figure 1
Total Harmonic Distortion and Noise vs Output Voltage	Figure 2
Total Harmonic Distortion and Noise vs Frequency	Figure 3
Total Harmonic Distortion and Noise vs Frequency	Figure 4
Crosstalk vs Frequency	Figure 5
Supply Rejection Ratio vs Frequency	Figure 6

11 Power Supply Recommendations

The TPA6138A2 DirectPath headphone amplifier requires adequate power supply decoupling to ensure that output noise and total harmonic distortion (THD) remain low. Use good low equivalent-series-resistance (ESR) ceramic capacitors (X5R material or better is required for best performance). Place a 2.2 µF capacitor within 5 mm of the VDD pin. Reducing the distance between the decoupling capacitor and VDD minimizes parasitic inductance and resistance, improving TPA6138A2 supply rejection performance. Use 0402 or smaller size capacitors if possible.

For additional supply rejection, connect an additional 10 μ F or higher value capacitor between VDD and ground. This will help filter lower frequency power supply noise. The high power supply rejection ratio (PSRR) of the TPA6138A2 makes the 10 μ F capacitor unnecessary in most applications.

Product Folder Links: TPA6138A2



12 Layout

12.1 Layout Guidelines

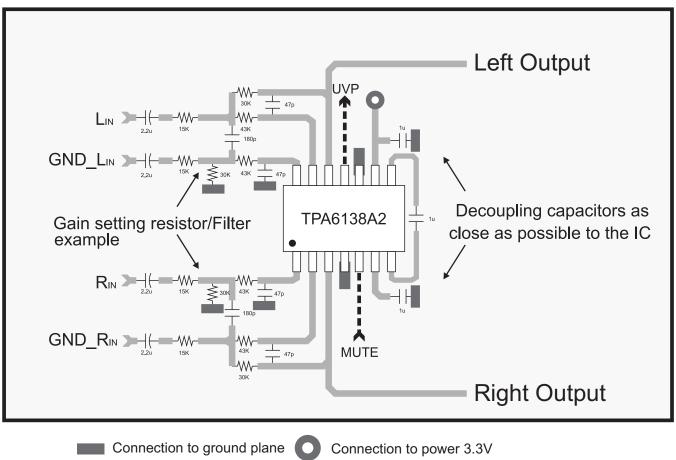
12.1.1 Gain-Setting Resistors

The gain-setting resistors, R_{IN} and R_{fb}, must be placed close to pins 13 and 17, respectively, to minimize capacitive loading on these input pins and to ensure maximum stability of the TPA6138A2. For the recommended PCB layout, see the TPA6138A2EVM User's Guide (SLOU305).

12.1.2 Decoupling Capacitors Placement

A low equivalent-series-resistance (ESR) ceramic capacitor, typically 1 µF, placed as close as possible to the device VDD lead works best. Placing this decoupling capacitor close to the TPA6138A2 is important for the performance of the amplifier. For filtering lower-frequency noise signals, a 10-µF or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device

12.2 Layout Example



Top layer traces

Top layer ground plane



13 Device and Documentation Support

13.1 Device Support

13.1.1 Development Support

For the TPA6138A2EVM and Gerber files, go to www.ti.com/tool/TPA6138A2EVM.

13.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community T's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.3 Trademarks

DirectPath, E2E are trademarks of Texas Instruments. WEBENCH is a registered trademark of Texas Instruments. Blu-ray Disc is a trademark of Blu-ray Disc Association. All other trademarks are the property of their respective owners.

13.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.5 Glossary

SLYZ022 — TI Glossarv.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2011-2015, Texas Instruments Incorporated



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
HPA01075PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPA6138	Samples
TPA6138A2PW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPA6138	Samples
TPA6138A2PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPA6138	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

10-Dec-2020

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

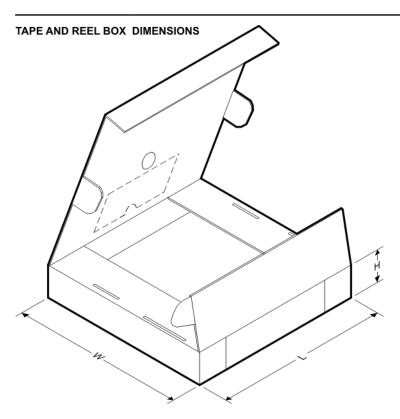
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA6138A2PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 5-Jan-2022



*All dimensions are nominal

ĺ	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	TPA6138A2PWR	TSSOP	PW	14	2000	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TPA6138A2PW	PW	TSSOP	14	90	530	10.2	3600	3.5

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated